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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

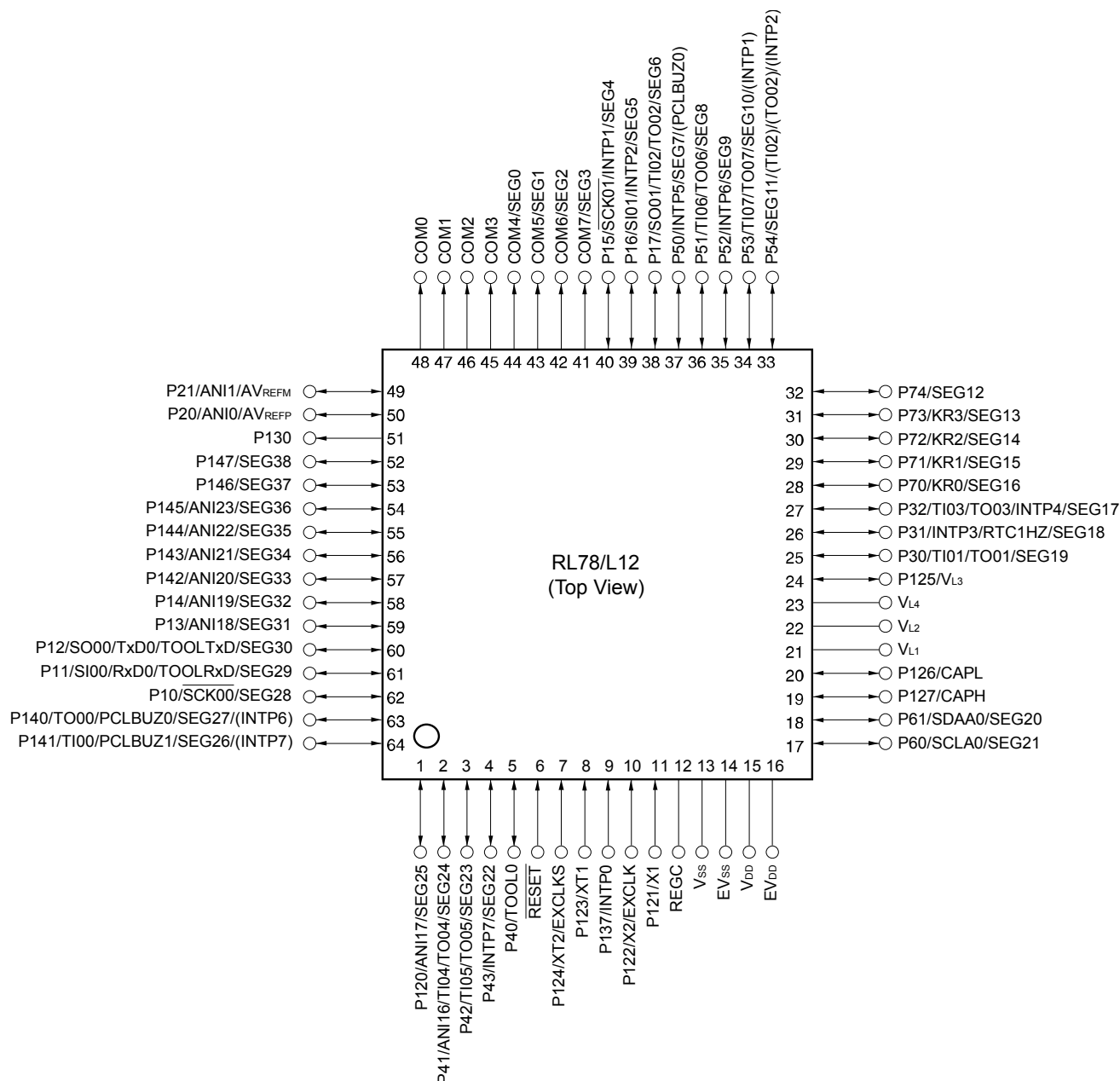
### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	24MHz
Connectivity	CSI, I <sup>2</sup> C, LINbus, UART/USART
Peripherals	DMA, LCD, LVD, POR, PWM, WDT
Number of I/O	47
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 10x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LFQFP (10x10)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10rlagfb-v0">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10rlagfb-v0</a>

- 64-pin plastic LQFP (fine pitch) (10 × 10)
- 64-pin plastic LQFP (12 × 12)

&lt;R&gt;



- Cautions**
1. Make EV<sub>ss</sub> pin the same potential as V<sub>ss</sub> pin.
  2. Make V<sub>DD</sub> pin the same potential as EV<sub>DD</sub> pin.
  3. Connect the REGC pin to V<sub>ss</sub> via a capacitor (0.47 to 1 μF).

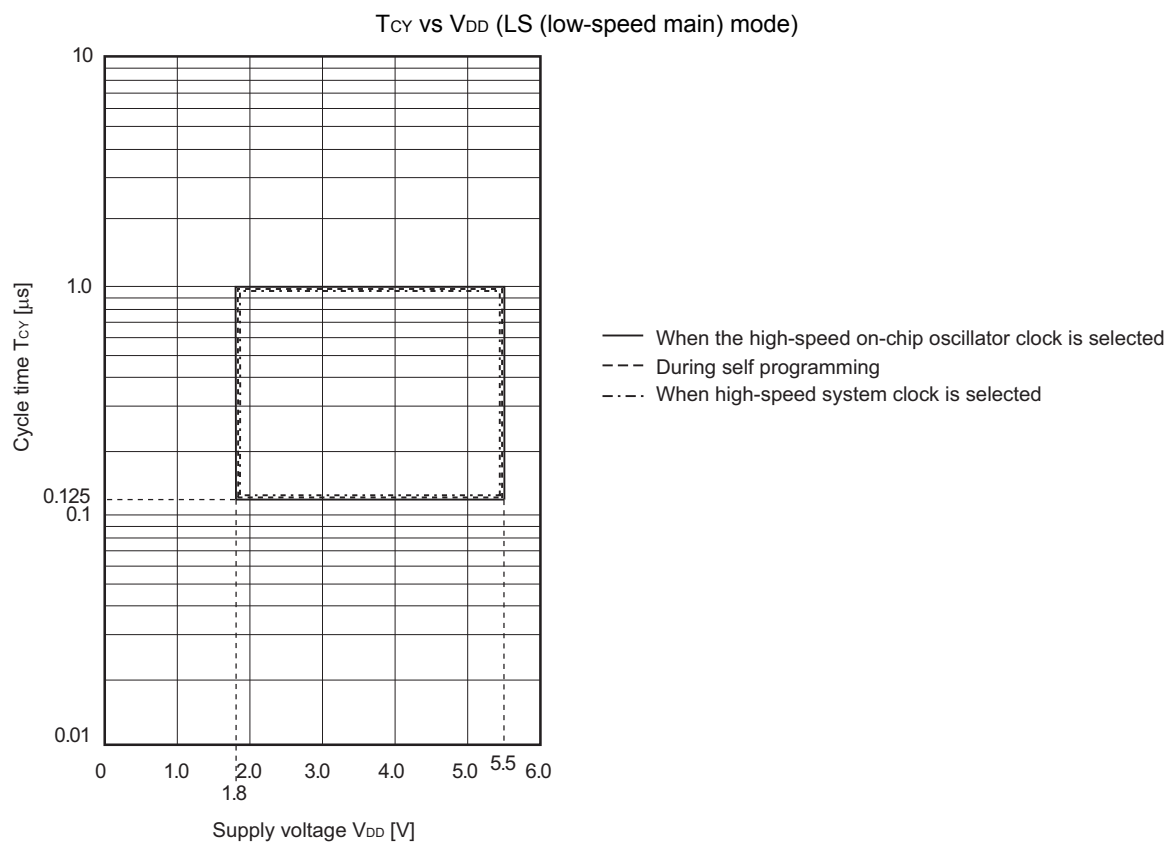
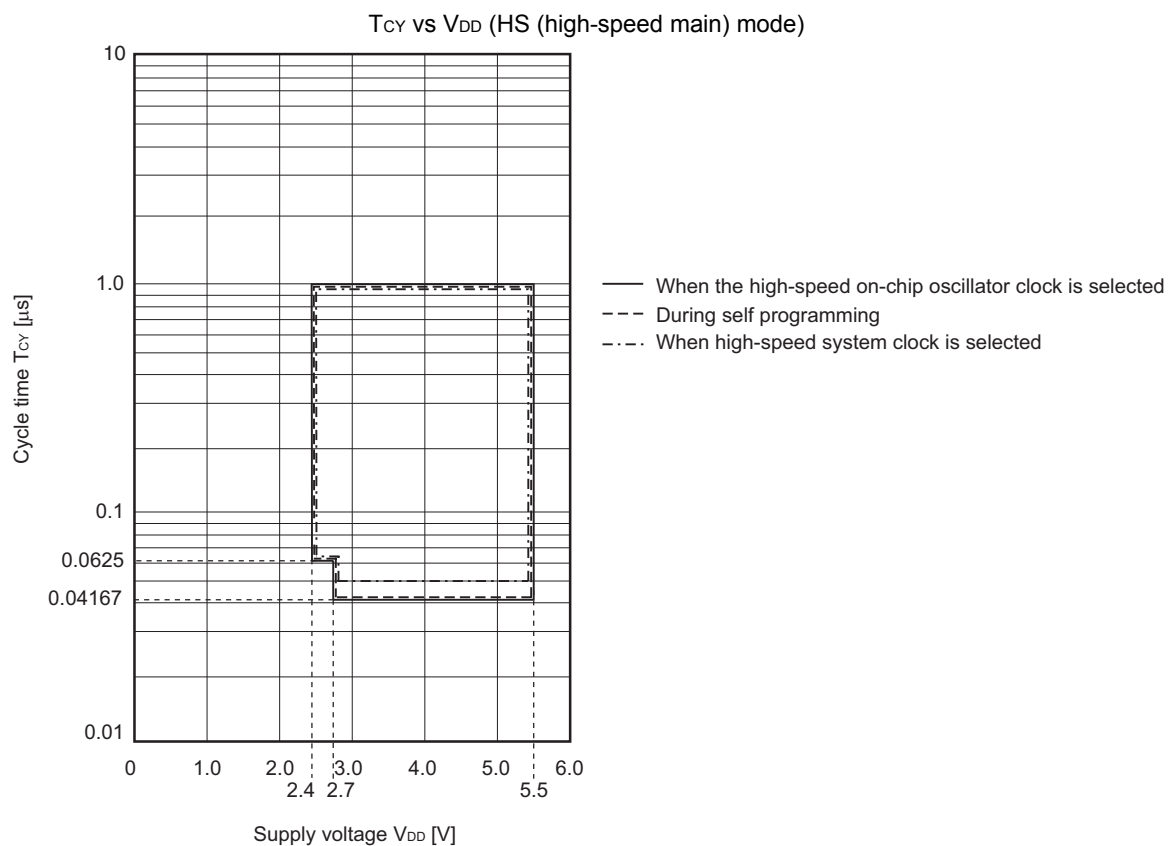
- Remarks**
1. For pin identification, see 1.4 Pin Identification.
  2. When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the V<sub>DD</sub> and EV<sub>DD</sub> pins and connect the V<sub>ss</sub> and EV<sub>ss</sub> pins to separate ground lines.
  3. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR).

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V)

(3/3)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	I <sub>FIL</sub> <sup>Note 1</sup>				0.20		μA
RTC operating current	I <sub>RTC</sub> Notes 1, 2, 3	f <sub>MAIN</sub> is stopped			0.08		μA
12-bit interval timer current	I <sub>IT</sub> Notes 1, 2, 4				0.08		μA
Watchdog timer operating current	I <sub>WDT</sub> Notes 1, 2, 5	f <sub>IL</sub> = 15 kHz			0.24		μA
A/D converter operating current	I <sub>ADC</sub> Notes 1, 6	When conversion at maximum speed	Normal mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 5.0 V		1.3	1.7	mA
			Low voltage mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 3.0 V		0.5	0.7	mA
A/D converter reference voltage current	I <sub>ADREF</sub> <sup>Note 1</sup>				75.0		μA
Temperature sensor operating current	I <sub>TMPS</sub> <sup>Note 1</sup>				75.0		μA
LVD operating current	I <sub>LVD</sub> Notes 1, 7				0.08		μA
Self-programming operating current	I <sub>FSP</sub> Notes 1, 9				2.50	12.20	mA
BGO operating current	I <sub>BGO</sub> Notes 1, 8				2.00	12.20	mA
LCD operating current	I <sub>LCD1</sub> Notes 11, 12	External resistance division method	V <sub>DD</sub> = EV <sub>DD</sub> = 5.0 V V <sub>L4</sub> = 5.0 V		0.04	0.20	μA
	I <sub>LCD2</sub> <sup>Note 11</sup>	Internal voltage boosting method	V <sub>DD</sub> = EV <sub>DD</sub> = 5.0 V V <sub>L4</sub> = 5.1 V (VLCD = 12H)		1.12	3.70	μA
			V <sub>DD</sub> = EV <sub>DD</sub> = 3.0 V V <sub>L4</sub> = 3.0 V (VLCD = 04H)		0.63	2.20	μA
	I <sub>LCD3</sub> <sup>Note 11</sup>	Capacitor split method	V <sub>DD</sub> = EV <sub>DD</sub> = 3.0 V V <sub>L4</sub> = 3.0 V		0.12	0.50	μA
SNOOZE operating current	I <sub>SNOZ</sub> <sup>Note 1</sup>	ADC operation	The mode is performed <sup>Note 10</sup>		0.50	0.60	mA
			The A/D conversion operations are performed, Low voltage mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 3.0 V		1.20	1.44	mA
		CSI/UART operation			0.70	0.84	mA

(Notes and Remarks are listed on the next page.)

**Minimum Instruction Execution Time during Main System Clock Operation**

## (4) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)

(2/2)

(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Transfer rate		Transmission	4.0 V ≤ EV <sub>DD</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V			Note 1		Note 1	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 1.4 kΩ, V <sub>b</sub> = 2.7 V			2.8 <sup>Note 2</sup>		2.8 <sup>Note 2</sup>	Mbps
			2.7 V ≤ EV <sub>DD</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V			Note 3		Note 3	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ, V <sub>b</sub> = 2.3 V			1.2 <sup>Note 4</sup>		1.2 <sup>Note 4</sup>	Mbps
			2.4 V ≤ EV <sub>DD</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V			Note 6		Note 6	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 5.5 kΩ, V <sub>b</sub> = 1.6 V			0.43 <sup>Note 7</sup>		0.43 <sup>Note 7</sup>	Mbps
			1.8 V ≤ EV <sub>DD</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V				Notes 5, 6	Notes 5, 6	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 5.5 kΩ, V <sub>b</sub> = 1.6 V				0.43 <sup>Note 7</sup>	0.43 <sup>Note 7</sup>	Mbps

**Notes 1.** The smaller maximum transfer rate derived by using f<sub>MCK</sub>/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 4.0 V ≤ EV<sub>DD</sub> ≤ 5.5 V and 2.7 V ≤ V<sub>b</sub> ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

- 2.** This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to Note 1 above to calculate the maximum transfer rate under conditions of the customer.

- Notes**
1. The first clock pulse is generated after this period when the start/restart condition is detected.
  2. The maximum value (MAX.) of  $t_{\text{HD:DAT}}$  is during normal transfer and a wait state is inserted in the  $\overline{\text{ACK}}$  (acknowledge) timing.

**Remark** The maximum value of  $C_b$  (communication line capacitance) and the value of  $R_b$  (communication line pull-up resistor) at that time in each mode are as follows.

Standard mode:  $C_b = 400 \text{ pF}$ ,  $R_b = 2.7 \text{ k}\Omega$

(2) I<sup>2</sup>C fast mode(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MIN.	MAX.	MIN.	
SCLA0 clock frequency	f <sub>SCL</sub>	Fast mode: f <sub>CLK</sub> ≥ 3.5 MHz	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0	400	0	400	0	400	kHz
			2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0	400	0	400	0	400	
			1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V			0	400	0	400	
Setup time of restart condition	t <sub>SU:STA</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		0.6		0.6		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		0.6		0.6		
		1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V				0.6		0.6		
Hold time <sup>Note 1</sup>	t <sub>HD:STA</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		0.6		0.6		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		0.6		0.6		
		1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V				0.6		0.6		
Hold time when SCLA0 = "L"	t <sub>LOW</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		1.3		1.3		1.3		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		1.3		1.3		1.3		
		1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V				1.3		1.3		
Hold time when SCLA0 = "H"	t <sub>HIGH</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		0.6		0.6		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		0.6		0.6		
		1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V				0.6		0.6		
Data setup time (reception)	t <sub>SU:DAT</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		100		100		100		ns
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		100		100		100		
		1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V				100		100		
Data hold time (transmission) <sup>Note 2</sup>	t <sub>HD:DAT</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0	0.9	0	0.9	0	0.9	μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0	0.9	0	0.9	0	0.9	
		1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V				0	0.9	0	0.9	
Setup time of stop condition	t <sub>SU:STO</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		0.6		0.6		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		0.6		0.6		
		1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V				0.6		0.6		
Bus-free time	t <sub>BUF</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		1.3		1.3		1.3		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		1.3		1.3		1.3		
		1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V				1.3		1.3		

**Notes** 1. The first clock pulse is generated after this period when the start/restart condition is detected.2. The maximum value (MAX.) of t<sub>HD:DAT</sub> is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.**Remark** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.Fast mode: C<sub>b</sub> = 320 pF, R<sub>b</sub> = 1.1 kΩ

(3) I<sup>2</sup>C fast mode plus(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCLA0 clock frequency	f <sub>SCL</sub>	Fast mode plus: f <sub>CLK</sub> ≥ 10 MHz 2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0	1000	—	—	—	—	kHz
Setup time of restart condition	t <sub>SU:STA</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0.26		—	—	—	—	μs
Hold time <sup>Note 1</sup>	t <sub>HD:STA</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0.26		—	—	—	—	μs
Hold time when SCLA0 = "L"	t <sub>LOW</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0.5		—	—	—	—	μs
Hold time when SCLA0 = "H"	t <sub>HIGH</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0.26		—	—	—	—	μs
Data setup time (reception)	t <sub>SU:DAT</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	50		—	—	—	—	μs
Data hold time (transmission) <sup>Note 2</sup>	t <sub>HD:DAT</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0	0.45	—	—	—	—	μs
Setup time of stop condition	t <sub>SU:STO</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0.26		—	—	—	—	μs
Bus-free time	t <sub>BUF</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0.5		—	—	—	—	μs

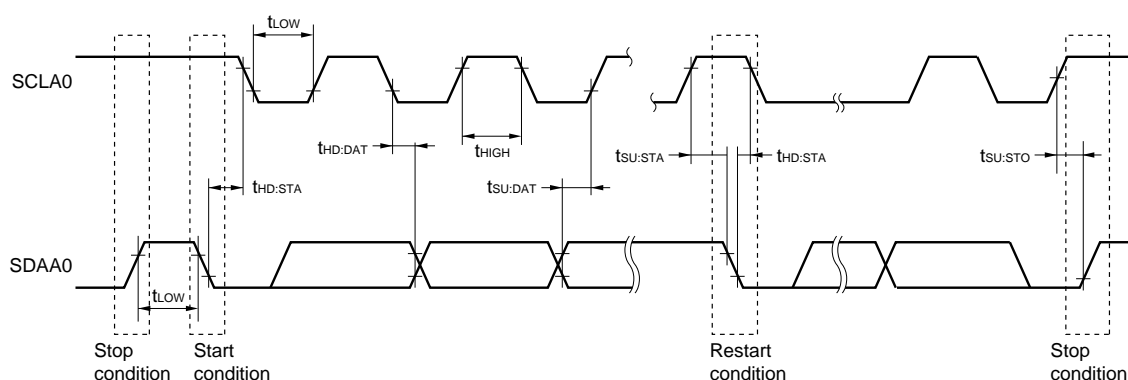
**Notes** 1. The first clock pulse is generated after this period when the start/restart condition is detected.2. The maximum value (MAX.) of t<sub>HD:DAT</sub> is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

**Caution** The values in the above table are applied even when bit 2 (PIOR2) in the peripheral I/O redirection register (PIOR) is 1. At this time, the pin characteristics (I<sub>OH1</sub>, I<sub>OL1</sub>, V<sub>OH1</sub>, V<sub>OL1</sub>) must satisfy the values in the redirect destination.

**Remark** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.

Fast mode plus: C<sub>b</sub> = 120 pF, R<sub>b</sub> = 1.1 kΩ

IICA serial transfer timing





## 2.7.2 Internal voltage boosting method

## (1) 1/3 bias method

(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
LCD output voltage variation range	V <sub>L1</sub>	C1 to C4 <sup>Note 1</sup> = 0.47 μF	VLCD = 04H	0.90	1.00	1.08	V
			VLCD = 05H	0.95	1.05	1.13	V
			VLCD = 06H	1.00	1.10	1.18	V
			VLCD = 07H	1.05	1.15	1.23	V
			VLCD = 08H	1.10	1.20	1.28	V
			VLCD = 09H	1.15	1.25	1.33	V
			VLCD = 0AH	1.20	1.30	1.38	V
			VLCD = 0BH	1.25	1.35	1.43	V
			VLCD = 0CH	1.30	1.40	1.48	V
			VLCD = 0DH	1.35	1.45	1.53	V
			VLCD = 0EH	1.40	1.50	1.58	V
			VLCD = 0FH	1.45	1.55	1.63	V
			VLCD = 10H	1.50	1.60	1.68	V
			VLCD = 11H	1.55	1.65	1.73	V
			VLCD = 12H	1.60	1.70	1.78	V
			VLCD = 13H	1.65	1.75	1.83	V
Doubler output voltage	V <sub>L2</sub>	C1 to C4 <sup>Note 1</sup> = 0.47 μF	2 V <sub>L1</sub> − 0.1	2 V <sub>L1</sub>	2 V <sub>L1</sub>	V	
Tripler output voltage	V <sub>L4</sub>	C1 to C4 <sup>Note 1</sup> = 0.47 μF	3 V <sub>L1</sub> − 0.15	3 V <sub>L1</sub>	3 V <sub>L1</sub>	V	
Reference voltage setup time <sup>Note 2</sup>	t <sub>WAIT1</sub>		5			ms	
Voltage boost wait time <sup>Note 3</sup>	t <sub>WAIT2</sub>	C1 to C4 <sup>Note 1</sup> = 0.47 μF	500			ms	

**Notes** 1. This is a capacitor that is connected between voltage pins used to drive the LCD.

C1: A capacitor connected between CAPH and CAPL

C2: A capacitor connected between V<sub>L1</sub> and GNDC3: A capacitor connected between V<sub>L2</sub> and GNDC4: A capacitor connected between V<sub>L4</sub> and GND

C1 = C2 = C3 = C4 = 0.47 μF±30%

- This is the time required to wait from when the reference voltage is specified by using the VLCD register (or when the internal voltage boosting method is selected [by setting the MDSET1 and MDSET0 bits of the LCDM0 register to 01B] if the default value reference voltage is used) until voltage boosting starts (VLCON = 1).
- This is the wait time from when voltage boosting is started (VLCON = 1) until display is enabled (LCDON = 1).

## 3.1 Absolute Maximum Ratings

Absolute Maximum Ratings (T<sub>A</sub> = 25°C)

(1/3)

Parameter	Symbols	Conditions	Ratings	Unit
Supply voltage	V <sub>DD</sub>	V <sub>DD</sub> = EV <sub>DD</sub>	-0.5 to +6.5	V
	EV <sub>DD</sub>	V <sub>DD</sub> = EV <sub>DD</sub>	-0.5 to +6.5	V
	EV <sub>SS</sub>		-0.5 to +0.3	V
REGC pin input voltage	V <sub>I REGC</sub>	REGC	-0.3 to +2.8 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 1</sup>	V
Input voltage	V <sub>I1</sub>	P10 to P17, P30 to P32, P40 to P43, P50 to P54, P70 to P74, P120, P125 to P127, P140 to P147	-0.3 to EV <sub>DD</sub> + 0.3 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>I2</sub>	P60, P61 (N-ch open-drain)	-0.3 to EV <sub>DD</sub> + 0.3 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>I3</sub>	P20, P21, P121 to P124, P137, EXCLK, EXCLKS, RESET	-0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
Output voltage	V <sub>O1</sub>	P10 to P17, P30 to P32, P40 to P43, P50 to P54, P60, P61, P70 to P74, P120, P125 to P127, P130, P140 to P147	-0.3 to EV <sub>DD</sub> + 0.3 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>O2</sub>	P20, P21	-0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
Analog input voltage	V <sub>AI1</sub>	ANI16 to ANI23	-0.3 to EV <sub>DD</sub> + 0.3 and -0.3 to AV <sub>REF</sub> (+) + 0.3 <sup>Notes 2, 3</sup>	V
	V <sub>AI2</sub>	ANI0, ANI1	-0.3 to V <sub>DD</sub> + 0.3 and -0.3 to AV <sub>REF</sub> (+) + 0.3 <sup>Notes 2, 3</sup>	V

**Notes 1.** Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.

**2.** Must be 6.5 V or lower.

**3.** Do not exceed AV<sub>REF</sub>(+) + 0.3 V in case of A/D conversion target pin.

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remarks 1.** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

**2.** AV<sub>REF</sub>(+) : + side reference voltage of the A/D converter.

**3.** V<sub>SS</sub> : Reference voltage

**Absolute Maximum Ratings (T<sub>A</sub> = 25°C)****(2/3)**

Parameter	Symbols	Conditions	Ratings	Unit
LCD voltage	V <sub>L1</sub>	V <sub>L1</sub> voltage <sup>Note 1</sup>	-0.3 to +2.8 and -0.3 to V <sub>L4</sub> + 0.3	V
	V <sub>L2</sub>	V <sub>L2</sub> voltage <sup>Note 1</sup>	-0.3 to V <sub>L4</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>L3</sub>	V <sub>L3</sub> voltage <sup>Note 1</sup>	-0.3 to V <sub>L4</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>L4</sub>	V <sub>L4</sub> voltage <sup>Note 1</sup>	-0.3 to +6.5	V
	V <sub>LCAP</sub>	CAPL, CAPH voltage <sup>Note 1</sup>	-0.3 to V <sub>L4</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>LOUT</sub>	COM0 to COM7, SEG0 to SEG38, output voltage	<div>External resistance division method</div> <div>Capacitor split method</div> <div>Internal voltage boosting method</div>	<div>-0.3 to V<sub>DD</sub> + 0.3<sup>Note 2</sup></div> <div>-0.3 to V<sub>DD</sub> + 0.3<sup>Note 2</sup></div> <div>-0.3 to V<sub>L4</sub> + 0.3<sup>Note 2</sup></div>

**Notes** 1. This value only indicates the absolute maximum ratings when applying voltage to the V<sub>L1</sub>, V<sub>L2</sub>, V<sub>L3</sub>, and V<sub>L4</sub> pins; it does not mean that applying voltage to these pins is recommended. When using the internal voltage boosting method or capacitance split method, connect these pins to V<sub>SS</sub> via a capacitor (0.47  $\mu$ F  $\pm$  30%) and connect a capacitor (0.47  $\mu$ F  $\pm$  30%) between the CAPL and CAPH pins.

2. Must be 6.5 V or lower.

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remark** V<sub>SS</sub> : Reference voltage

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V)

(3/3)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	I <sub>FIL</sub> <sup>Note 1</sup>				0.20		μA
RTC operating current	I <sub>RTC</sub> <sup>Notes 1, 2, 3</sup>	f <sub>MAIN</sub> is stopped			0.08		μA
12-bit interval timer current	I <sub>IT</sub> <sup>Notes 1, 2, 4</sup>				0.08		μA
Watchdog timer operating current	I <sub>WDT</sub> <sup>Notes 1, 2, 5</sup>	f <sub>IL</sub> = 15 kHz			0.24		μA
A/D converter operating current	I <sub>ADC</sub> <sup>Notes 1, 6</sup>	When conversion at maximum speed	Normal mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 5.0 V		1.3	1.7	mA
			Low voltage mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 3.0 V		0.5	0.7	mA
A/D converter reference voltage current	I <sub>ADREF</sub> <sup>Note 1</sup>				75.0		μA
Temperature sensor operating current	I <sub>TMPS</sub> <sup>Note 1</sup>				75.0		μA
LVD operating current	I <sub>LVD</sub> <sup>Notes 1, 7</sup>				0.08		μA
Self-programming operating current	I <sub>FSP</sub> <sup>Notes 1, 9</sup>				2.50	12.20	mA
BGO operating current	I <sub>BGO</sub> <sup>Notes 1, 8</sup>				2.50	12.20	mA
LCD operating current	I <sub>LCD1</sub> <sup>Notes 11, 12</sup>	External resistance division method	V <sub>DD</sub> = EV <sub>DD</sub> = 5.0 V V <sub>L4</sub> = 5.0 V		0.04	0.20	μA
	I <sub>LCD2</sub> <sup>Note 11</sup>	Internal voltage boosting method	V <sub>DD</sub> = EV <sub>DD</sub> = 5.0 V V <sub>L4</sub> = 5.1 V (VLCD = 12H)		1.12	3.70	μA
			V <sub>DD</sub> = EV <sub>DD</sub> = 3.0 V V <sub>L4</sub> = 3.0 V (VLCD = 04H)		0.63	2.20	μA
	I <sub>LCD3</sub> <sup>Note 11</sup>	Capacitor split method	V <sub>DD</sub> = EV <sub>DD</sub> = 3.0 V V <sub>L4</sub> = 3.0 V		0.12	0.50	μA
SNOOZE operating current	I <sub>SNOZ</sub> <sup>Note 1</sup>	ADC operation	The mode is performed <sup>Note 10</sup>		0.50	1.10	mA
			The A/D conversion operations are performed, Low voltage mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 3.0 V		1.20	2.04	mA
		CSI/UART operation			0.70	1.54	mA

(Notes and Remarks are listed on the next page.)

## 3.4 AC Characteristics

## 3.4.1 Basic operation

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ E<sub>VDD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS</sub> = 0 V)

Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Instruction cycle (minimum instruction execution time)	T <sub>CY</sub>	Main system clock (f <sub>MAIN</sub> ) operation	HS (high-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.04167	1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625	1	μs
		Subsystem clock (f <sub>SUB</sub> ) operation		2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	28.5	30.5	μs
		In the self programming mode	HS (high-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.04167	1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625	1	μs
External system clock frequency	f <sub>EX</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V		1.0		20.0	MHz
		2.4 V ≤ V <sub>DD</sub> < 2.7 V		1.0		16.0	MHz
	f <sub>EXS</sub>			32		35	kHz
External system clock input high-level width, low-level width	t <sub>EXH</sub> , t <sub>EXL</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V		24			ns
		2.4 V ≤ V <sub>DD</sub> < 2.7 V		30			ns
	t <sub>EXHS</sub> , t <sub>EXLS</sub>			13.7			μs
TI00 to TI07 input high-level width, low-level width	t <sub>TIH</sub> , t <sub>TIL</sub>			1/f <sub>MCK</sub> +10			ns
TO00 to TO07 output frequency	f <sub>TO</sub>	HS (high-speed main) mode	4.0 V ≤ E <sub>VDD</sub> ≤ 5.5 V			16	MHz
			2.7 V ≤ E <sub>VDD</sub> < 4.0 V			8	MHz
			2.4 V ≤ E <sub>VDD</sub> < 2.7 V			4	MHz
PCLBUZ0, PCLBUZ1 output frequency	f <sub>PCL</sub>	HS (high-speed main) mode	4.0 V ≤ E <sub>VDD</sub> ≤ 5.5 V			16	MHz
			2.7 V ≤ E <sub>VDD</sub> < 4.0 V			8	MHz
			2.4 V ≤ E <sub>VDD</sub> < 2.7 V			4	MHz
Interrupt input high-level width, low-level width	t <sub>INTH</sub> , t <sub>INTL</sub>	INTP0	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	1			μs
		INTP1 to INTP7	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	1			μs
Key interrupt input low-level width	t <sub>KR</sub>	KR0 to KR3	2.4 V ≤ E <sub>VDD</sub> ≤ 5.5 V	250			ns
RESET low-level width	t <sub>RSL</sub>			10			μs

**Remark** f<sub>MCK</sub>: Timer array unit operation clock frequency

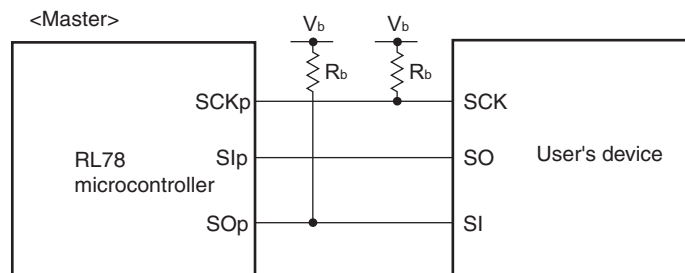
(Operation clock to be set by the CKS0n bit of timer mode register 0n (TMR0n).

n: Channel number (n = 0 to 7))

- Notes** 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.  
 2. When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Caution** Select the TTL input buffer for the SIp pin and the N-ch open drain output ( $V_{DD}$  tolerance (32- to 52-pin products)/ $EV_{DD}$  tolerance (64-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

CSI mode connection diagram (during communication at different potential)



- Remarks** 1.  $R_b[\Omega]$ : Communication line (SCKp, SOp) pull-up resistance,  
 $C_b[F]$ : Communication line (SCKp, SOp) load capacitance,  $V_b[V]$ : Communication line voltage  
 2. p: CSI number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1),  
 g: PIM and POM number (g = 1)  
 3.  $f_{MCK}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))

(2) I<sup>2</sup>C fast mode(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) Mode		Unit
				MIN.	MAX.	
SCLA0 clock frequency	f <sub>SCL</sub>	Fast mode:	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0	400	kHz
		f <sub>CLK</sub> ≥ 3.5 MHz	2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0	400	
Setup time of restart condition	t <sub>SU:STA</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		
Hold time <sup>Note 1</sup>	t <sub>HD:STA</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		
Hold time when SCLA0 = "L"	t <sub>LOW</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		1.3		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		1.3		
Hold time when SCLA0 = "H"	t <sub>HIGH</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		
Data setup time (reception)	t <sub>SU:DAT</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		100		ns
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		100		
Data hold time (transmission) <sup>Note 2</sup>	t <sub>HD:DAT</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0	0.9	μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0	0.9	
Setup time of stop condition	t <sub>SU:STO</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		0.6		
Bus-free time	t <sub>BUF</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V		1.3		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V		1.3		

- Notes**
- The first clock pulse is generated after this period when the start/restart condition is detected.
  - The maximum value (MAX.) of t<sub>HD:DAT</sub> is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

**Remark** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.

Fast mode: C<sub>b</sub> = 320 pF, R<sub>b</sub> = 1.1 kΩ

### 3.6 Analog Characteristics

#### 3.6.1 A/D converter characteristics

Classification of A/D converter characteristics

Input channel	Reference Voltage		
	Reference voltage (+) = AV <sub>REFP</sub> Reference voltage (-) = AV <sub>REFM</sub>	Reference voltage (+) = V <sub>DD</sub> Reference voltage (-) = V <sub>SS</sub>	Reference voltage (+) = V <sub>BGR</sub> Reference voltage (-) = AV <sub>REFM</sub>
ANI0, ANI1	–	Refer to <b>3.6.1 (3)</b> .	Refer to <b>3.6.1 (4)</b> .
ANI16 to ANI23	Refer to <b>3.6.1 (2)</b> .		
Internal reference voltage Temperature sensor output voltage	Refer to <b>3.6.1 (1)</b> .		–

(1) When reference voltage (+) = AV<sub>REFP</sub>/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AV<sub>REFM</sub>/ANI1 (ADREFM = 1), target pin : internal reference voltage, and temperature sensor output voltage

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, 2.4 V ≤ AV<sub>REFP</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V, Reference voltage (+) = AV<sub>REFP</sub>, Reference voltage (-) = AV<sub>REFM</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V	1.2	±3.5	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin: Internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.375	39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.5625	39	μs
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17	39	μs
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>ZS</sub>	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±0.25	%FSR
Full-scale error <sup>Notes 1, 2</sup>	E <sub>FS</sub>	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±0.25	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±2.5	LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±1.5	LSB
Analog input voltage	V <sub>AIN</sub>	Internal reference voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)	V <sub>BGR</sub> <sup>Note 4</sup>			V
		Temperature sensor output voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)	V <sub>TMPS25</sub> <sup>Note 4</sup>			V

**Notes** 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. When AV<sub>REFP</sub> < V<sub>DD</sub>, the MAX. values are as follows.

Overall error: Add ±1.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Zero-scale error/Full-scale error: Add ±0.05%FSR to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Integral linearity error/ Differential linearity error: Add ±0.5 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

4. Refer to **3.6.2 Temperature sensor/internal reference voltage characteristics**.



(4) When reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), reference voltage (-) = AV<sub>REFM</sub>/ANI1 (ADREFM = 1), target pin : ANI0, ANI16 to ANI23

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V, Reference voltage (+) = V<sub>BGR</sub><sup>Note 3</sup>, Reference voltage (-) = AV<sub>REFM</sub><sup>Note 4</sup> = 0 V, HS (high-speed main) mode)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8			bit
Conversion time	t <sub>CONV</sub>	8-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39	μs
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>zs</sub>	8-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±0.60	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	8-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±2.0	LSB
Differential linearity error <sup>Note 1</sup>	DLE	8-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±1.0	LSB
Analog input voltage	V <sub>AIN</sub>			0		V <sub>BGR</sub> <sup>Note 3</sup>	V

**Notes** 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. Refer to **3.6.2 Temperature sensor/internal reference voltage characteristics**.

4. When reference voltage (-) = V<sub>SS</sub>, the MAX. values are as follows.

Zero-scale error: Add ±0.35%FSR to the MAX. value when reference voltage (-) = AV<sub>REFM</sub>.

Integral linearity error: Add ±0.5 LSB to the MAX. value when reference voltage (-) = AV<sub>REFM</sub>.

Differential linearity error: Add ±0.2 LSB to the MAX. value when reference voltage (-) = AV<sub>REFM</sub>.

## (2) 1/4 bias method

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
LCD output voltage variation range	V <sub>L1</sub> <sup>Note 4</sup>	C1 to C5 <sup>Note 1</sup> = 0.47 μF	VLCD = 04H	0.90	1.00	1.08	V
			VLCD = 05H	0.95	1.05	1.13	V
			VLCD = 06H	1.00	1.10	1.18	V
			VLCD = 07H	1.05	1.15	1.23	V
			VLCD = 08H	1.10	1.20	1.28	V
			VLCD = 09H	1.15	1.25	1.33	V
			VLCD = 0AH	1.20	1.30	1.38	V
			VLCD = 0BH	1.25	1.35	1.43	V
			VLCD = 0CH	1.30	1.40	1.48	V
			VLCD = 0DH	1.35	1.45	1.53	V
			VLCD = 0EH	1.40	1.50	1.58	V
			VLCD = 0FH	1.45	1.55	1.63	V
			VLCD = 10H	1.50	1.60	1.68	V
			VLCD = 11H	1.55	1.65	1.73	V
			VLCD = 12H	1.60	1.70	1.78	V
			VLCD = 13H	1.65	1.75	1.83	V
Doubler output voltage	V <sub>L2</sub>	C1 to C5 <sup>Note 1</sup> = 0.47 μF	2 V <sub>L1</sub> – 0.08	2 V <sub>L1</sub>	2 V <sub>L1</sub>	V	
Tripler output voltage	V <sub>L3</sub>	C1 to C5 <sup>Note 1</sup> = 0.47 μF	3 V <sub>L1</sub> – 0.12	3 V <sub>L1</sub>	3 V <sub>L1</sub>	V	
Quadruply output voltage	V <sub>L4</sub> <sup>Note 4</sup>	C1 to C5 <sup>Note 1</sup> = 0.47 μF	4 V <sub>L1</sub> – 0.16	4 V <sub>L1</sub>	4 V <sub>L1</sub>	V	
Reference voltage setup time <sup>Note 2</sup>	t <sub>VWAIT1</sub>		5			ms	
Voltage boost wait time <sup>Note 3</sup>	t <sub>VWAIT2</sub>	C1 to C5 <sup>Note 1</sup> = 0.47 μF	500			ms	

**Notes** 1. This is a capacitor that is connected between voltage pins used to drive the LCD.

C1: A capacitor connected between CAPH and CAPL

C2: A capacitor connected between V<sub>L1</sub> and GNDC3: A capacitor connected between V<sub>L2</sub> and GNDC4: A capacitor connected between V<sub>L3</sub> and GNDC5: A capacitor connected between V<sub>L4</sub> and GND

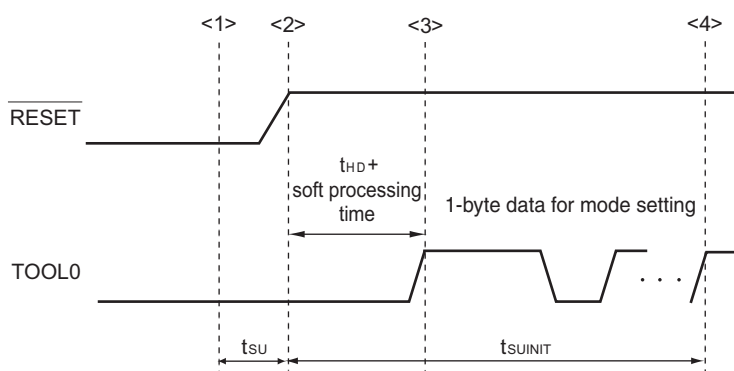
C1 = C2 = C3 = C4 = C5 = 0.47 μF ± 30%

- This is the time required to wait from when the reference voltage is specified by using the VLCD register (or when the internal voltage boosting method is selected [by setting the MDSET1 and MDSET0 bits of the LCDM0 register to 01B] if the default value reference voltage is used) until voltage boosting starts (VLCON = 1).
- This is the wait time from when voltage boosting is started (VLCON = 1) until display is enabled (LCDON = 1).
- V<sub>L4</sub> must be 5.5 V or lower.

## 3.11 Timing Specifications for Switching Flash Memory Programming Modes

(T<sub>A</sub> =  $-40$  to  $+105^{\circ}\text{C}$ ,  $2.4\text{ V} \leq \text{EV}_{\text{DD}} = \text{V}_{\text{DD}} \leq 5.5\text{ V}$ ,  $\text{V}_{\text{SS}} = \text{EV}_{\text{SS}} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Time to complete the communication for the initial setting after the external reset is released	t <sub>SUINIT</sub>	POR and LVD reset must be released before the external reset is released.			100	ms
Time to release the external reset after the TOOL0 pin is set to the low level	t <sub>SU</sub>	POR and LVD reset must be released before the external reset is released.	10			$\mu\text{s}$
Time to hold the TOOL0 pin at the low level after the external reset is released (excluding the processing time of the firmware to control the flash memory)	t <sub>HD</sub>	POR and LVD reset must be released before the external reset is released.	1			ms



&lt;1&gt; The low level is input to the TOOL0 pin.

&lt;2&gt; The external reset is released (POR and LVD reset must be released before the external reset is released.).

&lt;3&gt; The TOOL0 pin is set to the high level.

&lt;4&gt; Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

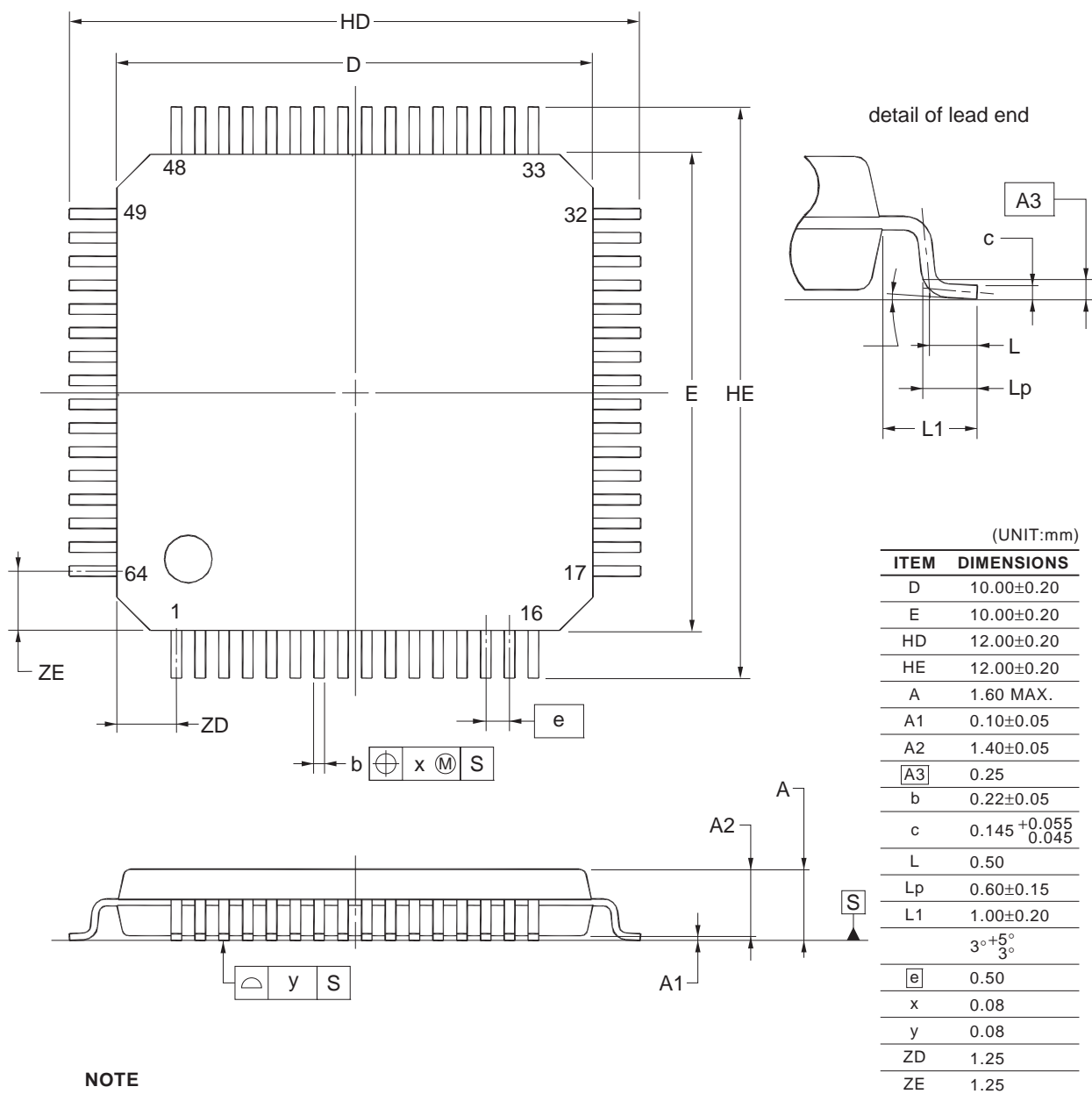
**Remark** t<sub>SUINIT</sub>: Communication for the initial setting must be completed within 100 ms after the external reset is released during this period.

t<sub>SU</sub>: Time to release the external reset after the TOOL0 pin is set to the low level

t<sub>HD</sub>: Time to hold the TOOL0 pin at the low level after the external reset is released (excluding the processing time of the firmware to control the flash memory)

R5F10RLAAFB, R5F10RLCAFB  
R5F10RLAGFB, R5F10RLCGFB

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LFQFP64-10x10-0.50	PLQP0064KF-A	P64GB-50-UEU-2	0.35



#### NOTE

Each lead centerline is located within 0.08 mm of its true position at maximum material condition.

The mark “<R>” shows major revised points. The revised points can be easily searched by copying an “<R>” in the PDF file and specifying it in the “Find what:” field.

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